IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Tetsuya Taki

Serial No.:

Not Yet Assigned

Group Art Unit:

Not Yet Assigned

Filing Date: Concurrently Herewith

Examiner:

Unknown

METHOD FOR PRODUCING P-TYPE GROUP III NITRIDE COMPOUND

SEMICONDUCTOR

Commissioner for Patents Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to Applicants' duty of disclosure under 37 CFR §1.56, Applicant respectfully brings the following documents listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. Copies of the listed documents are provided herewith for the convenience of the Examiner. In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3), the relevance of these documents is discussed on pages 2 and 3 of the subject application. Further, English-language Abstracts are attached to some the references.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the applicant is aware.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

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Respectfully submitted,

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INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional) T36-160821M/KOH	Application Number Not Yet Assigned		
Applicant(s) Tetsuya Taki			
Filing Date	Group Art Unit		
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				U.S. PAT	ENT DOCUMENTS				
AMINER NITIAL	REF	DOCUMENT NUMBER	DATE		NAME	CLASS	SUBCLASS	FILING I	
		5,306,662	04/26/1994	Nakam	ura, et al.				
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				FOREIG	ON PATENT DOCUMEN	TS			
	REF	DOCUMENT NUMBER	DATE	T	COUNTRY	CLASS	SUBCLASS	Trans	lation NO
		05-183189	07/23/1993	Japan				ABS	
		05-198841	08/06/1993	Japan				ABS	
		08-097471	04/12/1996	Japan					
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				ОТНЕ	R DOCUMENTS (Inclu	ding Author, Title	e, Date, Pertinent F	Pages, Etc.)	1 D4 1
		Nakamura, et al., "H No. 5A, May 1992, P	IOLE COMPENSA Pages 1258-1266	ATION M	ECHANISM OF P-TY	re gan film:	5°, Jpn. J. App.	rnys. voi. 3	i rait i
		Amano, et al., "GaN 1991, Pages 163-166	BLUE AND UV L	IGHT EN	IITTING DIODES WI	TH A PN JUNG	CTION", Oyo Bu	ituri, Vol. 6	0, No. 2,
EXAMIN	ER				DATE CONSIDEREI				
EXAMIN	ER: In	itial if citation considered, whet Include copy of this form with n	her or not citation is next communication t	in conform o applicant	ance with MPEP Section		rough citation if n	ot in conform	nance

Form PTO-A820 (also form PTO-1449)

P09A/REV04

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